




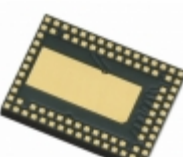
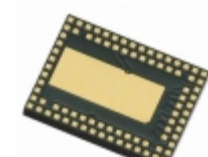
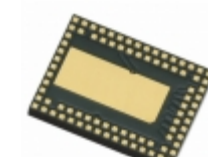

	<h2>SI1025X-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI1025X-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET 2P-CH 60V 0.19A SOT563F</p> <p>Datenblätter:  SI1025X-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 285582 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1025X-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2P-CH 60V 0.19A SOT563F
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	285582 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 P-Channel (Dual) 60V 190mA 250mW
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	190mA
Rds On (Max) @ Id, Vgs	4 Ohm @ 500mA, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.7nC @ 15V
Eingabekapazität (Ciss) (Max) @ Vds	23pF @ 25V
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI1025
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1025X-T1-E3TR

SI1025X-T1-E3 ist neu im Original, Suche SI1025X-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1025X-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1025X-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1025X-T1-E3 Vishay / Siliconix MOSFET 2P-CH 60V 0.19A SOT563F</p>	 <p>SI1025X VISHAY SI1025X VISHAY</p>	 <p>SI1025X-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 60V 0.19A SC-89</p>	 <p>SI1025X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 60V 0.19A SC-89</p>
 <p>SI1025-B-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1026-B-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1025-B-GM3R Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1026-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>

heiße Teile

Mehr

 SI1016X2-T1-GE3	 SI1021R-T1	 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1
 SI1022R-T1-E3	 SI1022R-T1-E3	 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-T1-E3
 SI1023CX-T1-GE3	 SI1023CX-T1-GE3	 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3
 SI1023X-T1-GE3	 SI1023X-T1-GE3	 SI1024-T1	 SI1024X-T1	 SI1024X-T1-E3
 SI1024X-T1-E3	 SI1024X-T1-GE3	 SI1024X-T1-GE3	 SI1024X-TI-GE3	 SI1025X-T1
 SI1025X-T1-E3	 SI1026X-T1	 SI1026X-T1-E3	 SI1026X-T1-E3	 SI1026X-T1-GE3
 SI1026X-T1-GE3	 SI1028X-T1-GE3	 SI1028X-T1-GE3	 SI1029X-T1-GE3	 SI1029X-T1-GE3
 SI1031R-T1	 SI1031R-T1-E3	 SI1031R-T1-E3	 SI1031R-T1-GE3	 SI1031R-T1-GE3
 SI1031X-T1	 SI1031X-T1-E3	 SI1031X-T1-E3	 SI1031X-T1-GE3	 SI1031X-T1-GE3
 SI1032R-T1	 SI1032R-T1-E3	 SI1032R-T1-E3	 SI1032R-T1-GE3	 SI1032R-T1-GE3

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